

isc Silicon NPN Power Transistors

DESCRIPTION

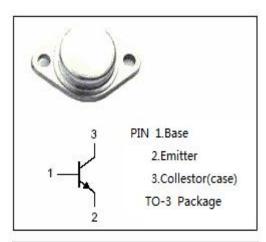
- · Collector-Emitter Breakdown Voltage-
 - : V_{(BR)CEO}= 100V(Min)
- · High Power Dissipation-
 - : P_C= 60W(Max)@T_C=25°C
- · Complement to Type 2SB653
- Minimum Lot-to-Lot variations for robust device performance and reliable operation

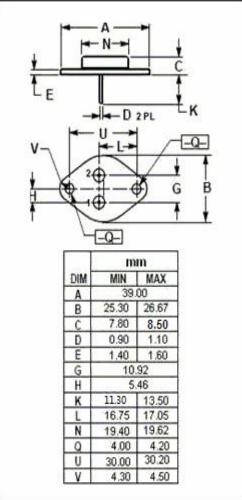
APPLICATIONS

• Designed for low frequency power amplifier applications.

ABSOLUTE MAXIMUM RATINGS(Ta=25℃)

SYMBOL	PARAMETER	VALUE	UNIT
V _{CBO}	Collector-Base Voltage	V	
V _{CEO}	Collector-Emitter Voltage	100	V
V _{ЕВО}	Emitter-Base Voltage	5	V
lc	Collector Current-Continuous	7	Α
I _{CM}	Collector Current-Peak	12	Α
Ів	Base Current-Continuous 2		Α
Pc	Collector Power Dissipation @Tc=25℃	60	W
TJ	Junction Temperature 150		$^{\circ}\!$
T _{stg}	Storage Temperature -55~150		°C







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2SD673

ELECTRICAL CHARACTERISTICS

Tj=25℃ unless otherwise specified

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SYMBOL	PARAMETER	CONDITIONS	MIN	TYP.	MAX	UNIT
V _{(BR)CEO}	Collector-Emitter Breakdown Voltage	I _C = 10mA; R _{BE} = ∞	100			V
V _{(BR)EBO}	Emitter-Base Breakdown Voltage	I _E = 1mA; I _C = 0	5			V
V _{CE(sat)}	Collector-Emitter Saturation Voltage	I _C = 5A; I _B = 0.5A			3.0	V
V _{BE(on)}	Base-Emitter On Voltage	I _C = 1A; V _{CE} = 5V			1.5	V
Ісво	Collector Cutoff Current	V _{CB} = 100V; I _E = 0			1	mA
h _{FE-1}	DC Current Gain	I _C = 1A; V _{CE} = 5V	60		200	
h _{FE-2}	DC Current Gain	I _C = 5A; V _{CE} = 5V	20			

♦ h_{FE-1} Classifications

В	С		
60-120	100-200		

NOTICE:

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